MITSUBISHI LASER DIODES

ML6XX25 SERIES

FOR OPTICAL INFORMATION SYSTEMS

TYPE NAME

ML60125R, ML601J25

DESCRIPTION

ML6XX25 is a high power AlGaAs semiconductor laser which provides a stable, single transverse mode oscillation with emission wavelength of 785nm and standard light output of 30mW. ML6XX25 is produced by the MOCVD crystal growth method which is excellent in mass production and characteristics uniformity. This is a high -performance , highly reliable , and long life semiconductor laser.

ABSOLUTE MAXIMUM RATINGS (Note 1)

FEATURES

- Output 30mW (CW) 45mW (pulse)
- Short astigmatic distance
- MQW * active layer
 - * : Multiple Quantum Well
- High volume production capacity
- Built-in monitor photodiode (ML60125R)

APPLICATION

Optical disc drive

Symbol	Parameter	Conditions	Ratings	Unit			
Ро	Light output power	CW	35	mW			
		Pulse(Note 2)	50	IIIVV			
VRL	Reverse voltage (laser diode)	-	2	V			
VRD(Note 3)	Reverse voltage (Photodiode)	-	30	V			
IFD(Note 3)	Forward current (Photodiode)	-	10	mA			
Тс	Case temperature	-	-40~ +60	°C			
Tstg	Storage temperature	-	-40~ +100	°C			

Note1: The maximum rating means the limitation over which the laser should not be operated even instant time, and this does not mean the guarantee of its lifetime. As for the reliability, please refer to the reliability report from Mitsubishi Semiconductor Quality Assurance Department.

Note2: TARGET SPEC /Condition Duty less than 50%, pulse width less than 1 μs Note3: Applicable to ML60125R

ELECTRICAL/OPTICAL CHARACTERISTICS (Tc=25°C)

Symbol	Parameter	Test conditions	Min.	Тур.	Max	Unit
lth	Threshold current	CW	-	35	50	mA
Іор	Operation current	CW,Po=30mW	-	85	110	mA
	Slope efficiency	CW,Po=30mW	-	0.6	-	mW/mA
Vop	Operating voltage	CW,Po=30mW	-	2.0	2.5	V
р	Peak wavelength	CW,Po=30mW	775	785	795	nm
//	Beam divergence angle (parallel)	CW,Po=30mW	9	10	11	deg.
Ť	Beam divergence angle (perpendicular)	CW,Po=30mW	22	25	28	deg.
Im(Note 4)	Monitoring output current (Photodiode)	CW,Po=30mW,VRD=1V RL=10(Note 5)	-	0.4	-	mA
ID(Note 4)	Dark current (Photodiode)	VRD=10V	-	-	0.5	μA
Ct(Note 4)	Capacitance (Photodiode)	VRD=5V	-	7	-	pF

Note 4: Applicable to ML60125R

Note 5:RL=the load resistance of photodiode



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